Vishay General Semiconductor

Enhanced isoCink+[™] Bridge Rectifiers



www.vishay.com

isoCink+™ Case Style BU



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)} 15 A					
V _{RRM}	600 V, 800 V, 1000 V				
I _{FSM}	200 A				
I _R	5 μΑ				
V _F at I _F = 7.5 A	0.87 V				
T _J max.	150 °C				
Package	BU				
Circuit configurations	In-line				

FEATURES

- UL recognition file number E312394
- Thin single in-line package
- Glass passivated chip junction
- Superior thermal conductivity
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances and white-goods applications.

MECHANICAL DATA

Case: BU

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meet JESD 201 class 1A whisker test

Polarity: as marked on body

Mounting Torque: 10 cm-kg (8.8 inches-lbs) max.

Recommended	lorque: 5./	cm-kg (o inches-lbs)

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	BU1506	BU1508	BU1510	UNIT
Maximum repetitive peak reverse voltage		V _{RRM}	600	800	1000	V
	$T_{C} = 80 \ ^{\circ}C \ ^{(1)}$		15			А
	$T_A = 25 \ ^{\circ}C \ ^{(2)}$	I _O	1 ₀ 3.4			
Non-repetitive peak forward surge current 8.3 ms single sine-wave, $T_J = 25 \text{ °C}$		I _{FSM}	200		А	
Rating for fusing (t < 8.3 ms) T_J = 25 °C		l ² t	160		A ² s	
Operating junction and storage temperature range	je	T _J , T _{STG}		-55 to +150		°C

Notes

⁽¹⁾ With 60 W air cooled heatsink

(2) Without heatsink, free air

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COMPLIANT HALOGEN



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode ⁽¹⁾	l _F = 7.5 A	T _A = 25 °C	V _F	0.97	1.05	V	
		T _A = 125 °C		0.87	0.95		
Maximum reverse current per diode	rated V _R	T _A = 25 °C	- I _R	-	5.0	μA	
		T _A = 125 °C		90	250		
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	70	-	pF	

Note

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⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	OL BU1506 BU1508 BU1510 UN				
Typical thermal resistance	R _{θJC} ⁽¹⁾	2.5			°C/W	
	R _{0JA} ⁽²⁾	20				

Notes

⁽¹⁾ With 60 W air cooled heatsink

(2) Without heatsink, free air

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
BU1506-E3/45	4.75	45	20	Tube			
BU1506-E3/51	4.75	51	250	Paper tray			
BU1506-M3/45	4.75	45	20	Tube			



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise specified)

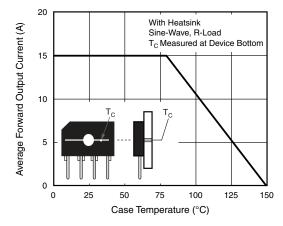


Fig. 1 - Derating Curve Output Rectified Current

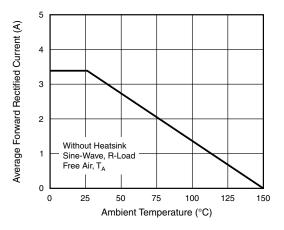


Fig. 2 - Forward Current Derating Curve

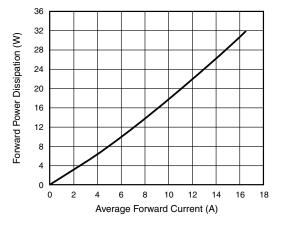


Fig. 3 - Forward Power Dissipation

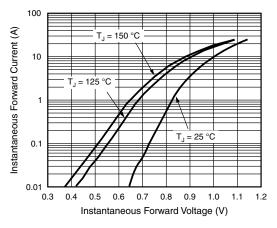


Fig. 4 - Typical Forward Characteristics Per Diode

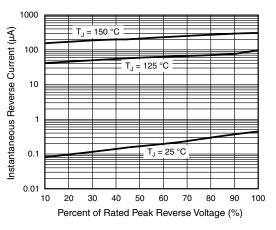


Fig. 5 - Typical Reverse Characteristics Per Diode

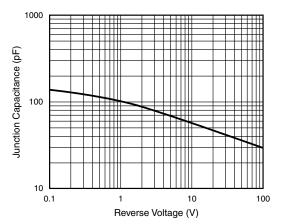


Fig. 6 - Typical Junction Capacitance Per Diode

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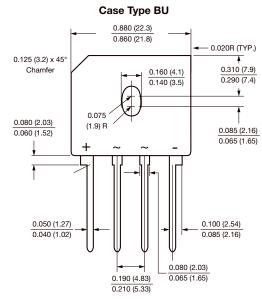
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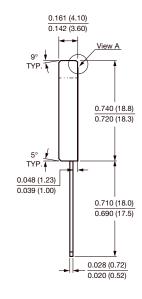
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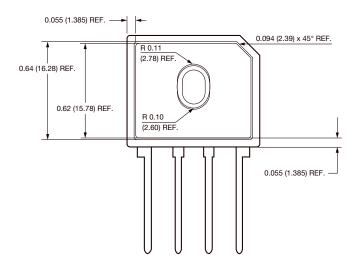
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Polarity shown on front side of case, positive lead beveled corner



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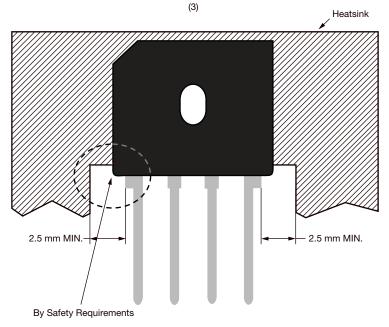
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APPLICATION NOTE

- 1. Device UL approved for safety use dielectric strength of 1500 V.
- 2. If device is mounted in Floating Ground (F. G.) application, insulator is recommended to use to meet safety requirement.
- 3. Heat sink shape recommendation:





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